L Number	Hits	Search Text	DB	Time stamp
- Mariner	162	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/25
	102	or tetrapropoxysilane or	US-PGPUB;	17:16
		tetrabutoxysilane or alkoxide) same	EPO; JPO;	17:10
		(single adj crystal or epitax\$3)	DERWENT;	
		(bright day or operatings)	IBM TDB	
_	97	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/25
		or tetrapropoxysilane or	US-PGPUB;	17:21
		tetrabutoxysilane or alkoxide) same	EPO; JPO;	
		(single adj crystal or epitax\$3) same	DERWENT;	
		film	IBM TDB	
_	27	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	11:15
		tetrabutoxysilane) same (single adj	EPO; JPO;	
		crystal or epitax\$3) same film	DERWENT;	
			IBM_TDB	
_	8	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/25
•		or tetrapropoxysilane or	US-PGPUB;	17:42
		tetrabutoxysilane) same (single adj	EPO; JPO;	
		crystal or epitax\$3) and (atmospheric adj	DERWENT;	
		pressure or one adj atm)	IBM_TDB	
-	29		USPAT;	2002/07/25
	1	or tetrapropoxysilane or	US-PGPUB;	17:48
		tetrabutoxysilane) same (single adj	EPO; JPO;	
		crystal or epitax\$3) and pressure	DERWENT;	
	101	45 5 43 43 43 45 5 5 5 5 5 5 5 5 5 5 5 5	IBM_TDB	2002/07/25
_	191		USPAT;	2002/07/25
		or tetrapropoxysilane or	US-PGPUB;	17:53
•		tetrabutoxysilane) same (oxygen or "o.sub.2") same pressure	EPO; JPO; DERWENT;	
		o.sub.2 ) same pressure	IBM TDB	
·	103	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
. —	103	or tetrapropoxysilane or	US-PGPUB;	09:50
		tetrabutoxysilane) same (oxygen or	EPO; JPO;	05.30
		"o.sub.2") same pressure and	DERWENT;	
		(438/\$4.ccls. or 117/\$4.ccls)	IBM TDB	1
_	7		USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	11:26
		tetrabutoxysilane) and atomic adj layer	EPO; JPO;	
		adj epitax\$3	DERWENT;	<del> </del>
			IBM_TDB	
-	18	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	11:31
		tetrabutoxysilane) and atomic adj layer	EPO; JPO;	
			DERWENT;	
		41 42 43 43 43	IBM_TDB	2002/07/26
-	28	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	11:37
		tetrabutoxysilane) same (epitax\$3)	EPO; JPO; DERWENT;	
			IBM TDB	
<u>·</u>	7	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
	'	or tetrapropoxygilane or	US-PGPUB;	11:39
		tetrabutoxysilane or (silicon adj	EPO; JPO;	
		alkoxide)) near20 (epitax\$3)	DERWENT;	
			IBM TDB	
_	29	(tetramethoxysilane or tetraethoxysilane	USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	11:48
		tetrabutoxysilane or (silicon adj	EPO; JPO;	
	]	alkoxide)) and 117/\$4.ccls.	DERWENT;	
			IBM_TDB	
_	52	(normal adj pressure adj cvd ) and	USPĀT;	2002/07/26
•		(tetramethoxysilane or tetraethoxysilane	US-PGPUB;	14:41
		or tetrapropoxysilane or	EPO; JPO;	
		tetrabutoxysilane) and pressure	DERWENT;	
			IBM_TDB	

	123	'	USPAT;	2002/07/26
	i	or tetrapropoxysilane or	US-PGPUB;	15:02
		tetrabutoxysilane) and (oxide same	EPO; JPO;	
		epitax\$4)	DERWENT;	
			IBM_TDB	
-	26	' ' ' ' - ' - ' - ' - ' - ' - ' - ' -	USPAT;	2002/07/26
		or tetrapropoxysilane or	US-PGPUB;	15:29
•		tetrabutoxysilane) and (117/\$4.ccls.)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	253	(silicon adj (dioxide or oxide)) same	USPĀT;	2002/07/26
		epitax\$4 and 117/\$4.ccls.	US-PGPUB;	15:34
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	113	(silicon adj (dioxide or oxide)) same	USPAT;	2002/07/26
		epitax\$4 and 117/\$4.ccls. and cvd	US-PGPUB;	15:36
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	66	(silicon adj (dioxide or oxide)) near20	USPAT;	2002/07/26
		epitax\$4 and 117/\$4.ccls. and cvd	US-PGPUB;	15:50
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	1
-	140	(silicon adj (dioxide or oxide)) near40	USPAT;	2002/07/26
		crystal\$5 and 117/\$4.ccls. and cvd	US-PGPUB;	17:30
			EPO; JPO;	
			DERWENT;	
		·	IBM_TDB	
-	2	ethyl\$1silicate and 117/\$4.ccls.	USPAT;	2002/07/26
			US-PGPUB;	17:37
			EPO; JPO;	
			DERWENT;	
			IBM TDB	